## CLAIMS

What is claimed is:

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5 1. A method for growing a transparent layer on a LED substrate, comprising:

providing a supersaturated solution, wherein said supersaturated solution comprises Sb as a solvent;

immersing the LED substrate into said supersaturated solution; and

growing the transparent layer onto the LED substrate.

- 2. The method according to claim 1, wherein said supersaturated solution further comprises In as the solvent.
- 3. The method according to claim 1, wherein said supersaturated solution further comprises a metallic dopant.
- 4. The method according to claim 3, wherein said metallic 20 dopant comprises Zn.
  - 5. The method according to claim 4, wherein said Zn is in an amount of 1/1000 to 1/10 by weight of the Sb.
- 6. The method according to claim 1, wherein said step of immersing the LED substrate into said supersaturated solution is performed under a temperature of about 500℃ to 1000℃.

7. A method for growing a transparent layer onto a LED substrate, comprising:

providing a supersaturated solution, wherein said supersaturated solution comprises Sb as a solvent;

immersing the LED substrate into said supersaturated solution; growing a first transparent layer onto the LED substrate, wherein the first transparent layer has a first thickness;

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immersing the LCD substrate with the first transparent layer into said supersaturated solution; and

growing a secondary transparent layer onto the first transparent layer on the LED substrate, wherein the secondary transparent layer has a secondary thickness.

- 8. The method according to claim 7, wherein said supersaturated solution further comprises In as the solvent.
  - 9. The method according to claim 7, wherein said supersaturated solution further comprises a metallic dopant.
- 20 10. The structure according to claim 8, wherein said metallic dopant comprises Zn.
  - 11. The method according to claim 10, wherein said Zn is in an amount of 1/1000 to 1/10 by weight of the Sb.
  - 12. The method according to claim 7, wherein said step of immersing the LED substrate into said supersaturated solution is performed under a temperature of about  $500^{\circ}$ C to  $1000^{\circ}$ C.

13. A method for growing a transparent layer onto a LED substrate, comprising:

providing a supersaturating solution, wherein said supersaturating solution comprises Sb and In as a solvent, GaP as a solute, and Zn as a dopant;

immersing the LED substrate into said supersaturated solution; and

growing the transparent layer onto the LED substrate.

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- 14. The method according to claim 13, wherein said Zn is in an amount of 1/1000 to 1/10 by weight of Sb of the supersaturated solution in the LPE process.
- 15. The method according to claim 13, wherein said step of immersing the LED substrate into said supersaturated solution is performed under a temperature of about 500℃ to 1000℃.
- 16. The method according to claim 13, wherein said growing the transparent layer comprises the following steps:

growing a first transparent layer onto the LED substrate;

immersing the LED substrate with said first transparent layer into said supersaturated solution; and

growing a secondary transparent layer onto said first 25 transparent layer.

17. A structure of a LED device, the structure comprising: a LED substrate; and

- a transparent layer on said LED substrate, wherein said transparent layer comprises a metallic Zn dopant.
- 18. The structure according to claim 17, wherein said 5 transparent layer is formed by LPE process.
  - 19. The structure according to claim 17, wherein said transparent layer is formed by LPE process utilizing a supersaturated solution comprising metallic antimony (Sb) and indium (In) as a solvent.
  - 20. The structure according to claim 18, wherein said Zn dopant is in an amount of 1/1000 to 1/10 by weight of a solvent of a supersaturated solution in the LPE process.
- 15 21. The structure according to claim 19, wherein said Zn dopant is in an amount of 1/1000 to 1/10 by weight of Sb of the supersaturated solution in the LPE process.

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